



DMT3004LPS

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max Tc = +25°C
	3.8mΩ @ V <sub>GS</sub> = 10V	140A
30V	6mΩ @ V <sub>GS</sub> = 4.5V	110A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Backlighting
- Power management functions
- DC-DC converters

# PowerDI5060-8

**30V N-CHANNEL ENHANCEMENT MODE MOSFET** 

### **Features and Benefits**

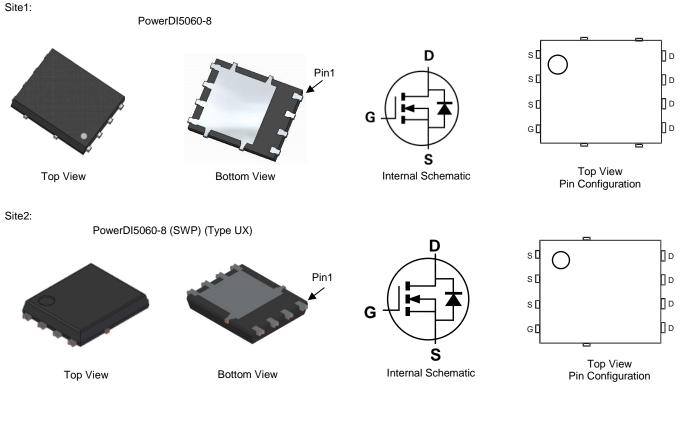
- Low RDS(ON) Minimizes On-State Losses
- Excellent Q<sub>gd</sub> x R<sub>DS(ON)</sub> Product (FOM)
- Advanced Technology for DC-DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- 100% Unclamped Inductive Switching Ensures More Reliability
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (@)
- Weight: 0.097 grams (Approximate)



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Notes:

# Ordering Information (Note 4)

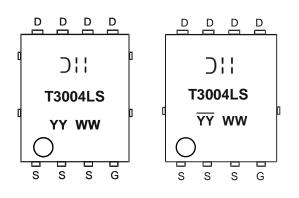
Part Number	Deskare	Packing		
Part Number	Package	Qty.	Carrier	
DMT3004LPS-13	PowerDI5060-8	2,500	Tape & Reel	
DMT3004LPS-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



# Maximum Ratings ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	30	V
Gate-Source Voltage		Vgss	+20 -16	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 5)	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	21 17	А
Continuous Drain Current, V <sub>GS</sub> = 10V	Tc = +25°C Tc = +70°C	ID	140 110	А
Maximum Continuous Body Diode Forward Current (Note 5)	T <sub>A</sub> = +25°C	ls	3	А
Maximum Continuous Body Diode Forward Current	$T_C = +25^{\circ}C$	ls	48	А
Maximum Body Diode Forward Pulse Current	Tc = +25°C	lsм	180	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	180	А
Avalanche Current, L=0.3mH		las	27	А
Avalanche Energy, L=0.3mH		Eas	110	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation	T <sub>A</sub> = +25°C (Note 5)	PD	2.7	W
	Tc = +25°C		113	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	47	°C/W
Thermal Resistance, Junction to Case		R <sub>θJC</sub>	1.1	C/VV
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Note: 5. R<sub>0JA</sub> is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1in. square copper plate. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.



# Electrical Characteristics (T<sub>A</sub> = +25°C, unless otherwise specified.)

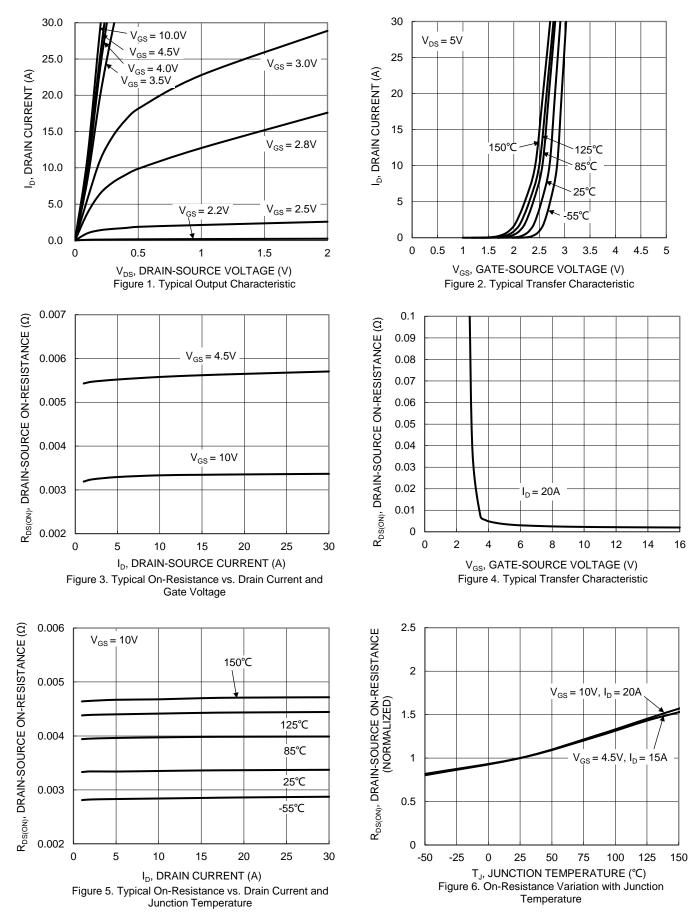
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					-	
Drain-Source Breakdown Voltage	BVDSS	30	_	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS			1	μA	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>			±100	nA	V <sub>GS</sub> = +20V, V <sub>DS</sub> = 0V V <sub>GS</sub> = -16V, V <sub>DS</sub> = 0V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	Vgs(th)	1	_	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance	5	—	—	3.8		VGS = 10V, ID = 20A
Static Drain-Source On-Resistance	RDS(ON)		_	6	mΩ	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 7A
Diode Forward Voltage	Vsd		0.70	1	V	$V_{GS} = 0V$ , $I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss	—	2,370	—		$V_{DS} = 15V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	_	1,360	—	pF	
Reverse Transfer Capacitance	Crss	—	240	—		
Gate Resistance	Rg	—	0.7	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	43.7	—		
Gate-Source Charge	Qgs		6.9	—	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 20A
Gate-Drain Charge	Q <sub>gd</sub>	—	8	—		
Turn-On Delay Time	tD(ON)		6.2	—		
Turn-On Rise Time	tR		4.2	—		$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 15V, \ V_{\text{GS}} = 10V, \\ R_{\text{G}} = 3\Omega, \ R_{\text{L}} = 0.75\Omega \end{array}$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	21	—	ns	
Turn-Off Fall Time	tF	_	8	—	1	
Body Diode Reverse Recovery Time	trr	_	25	—	ns	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	37	—	nC	I <sub>F</sub> = 15A, di/dt = 500A/μs

 Notes:
 6. Short duration pulse test used to minimize self-heating effect.

 7. Guaranteed by design. Not subject to product testing.



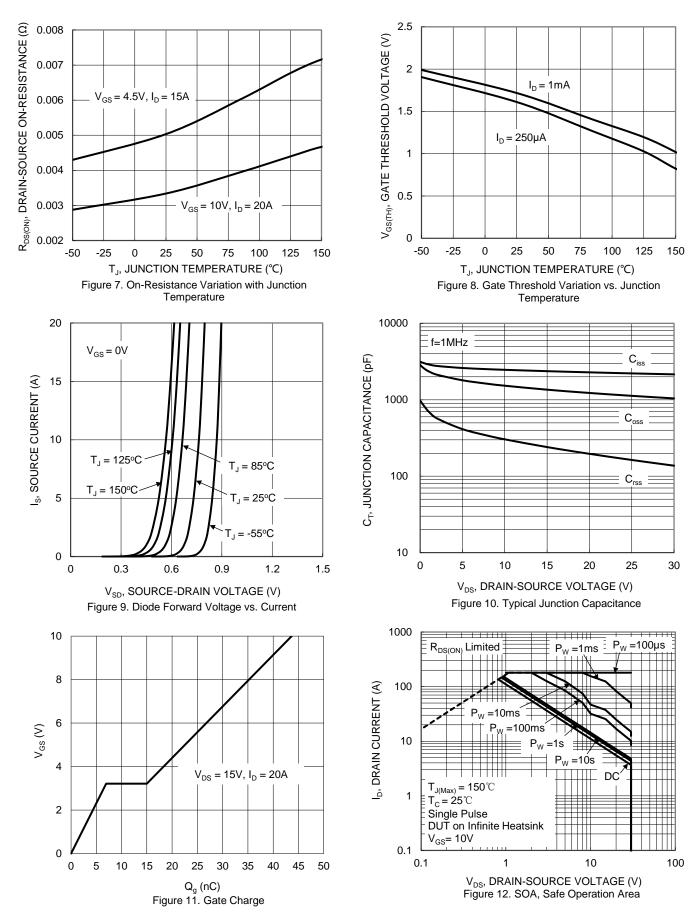
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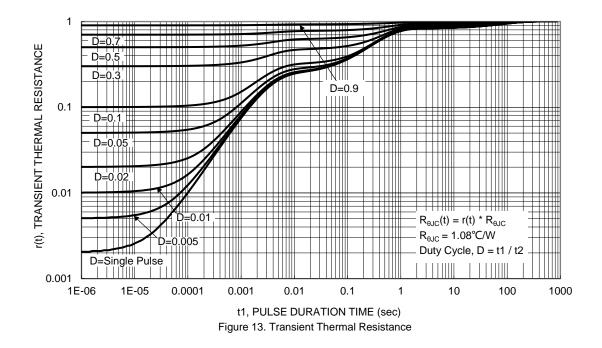


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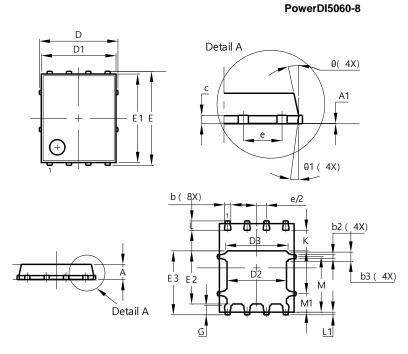




# **Package Outline Dimensions**

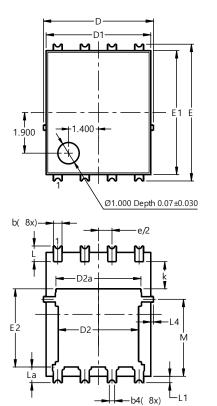
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site1:

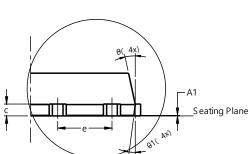


PowerDI5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	-	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D	-	5.15 BSC		
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
Е		6.15 BSC		
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
e		1.27 BSC		
G	0.51	0.71	0.61	
ĸ	0.51	-	-	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
Μ	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
All	All Dimensions in mm			

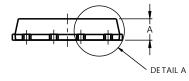
Site2:



PowerDI5060-8 (SWP) (Type UX)



DETAIL A



PowerDI5060-8 (SWP) (Type UX)				
Dim	Min Max Typ			
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	(	).25REF	-	
С	0.230	0.330		
D	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
Е	6	.40 BS0	2	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е		.27BSC	<u>)                                    </u>	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	-	.050RE		
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

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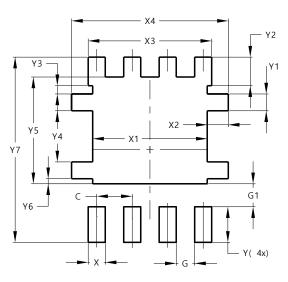


# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site1:

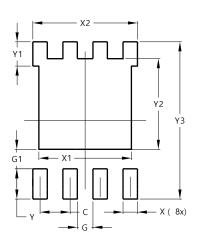
#### PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site2:

#### PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value (in mm)
C	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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